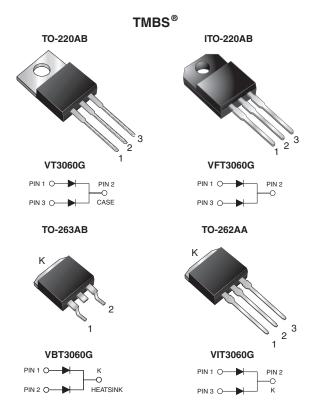


Vishay General Semiconductor

Dual High Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.40 \text{ V}$ at $I_F = 5 \text{ A}$



PRIMARY CHARACTERISTICS						
I _{F(AV)}	2 x 15 A					
V _{RRM}	60 V					
I _{FSM}	150 A					
V _F at I _F = 15 A	0.61 V					
T _J max.	150 °C					
Package	TO-220AB, ITO-220AB, TO-263AB, TO-262AA					
Diode variations	Common cathode					

FEATURES





- · Low forward voltage drop, low power losses
- zen ierrara reitage arep, ien pen
- High efficiency operation



- Meets MSL level 1, per J-STD-020, RC LF maximum peak of 245 °C (for TO-263AB compackage)
- Not recommended for PCB bottom side wave mounting
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB, ITO-220AB and TO-262AA package)
- Material categorization: For definitions of compliance please see <u>www.vishav.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in high frequency inverters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters and reverse battery protection.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, TO-263AB and TO-262AA

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS compliant and commercial grade

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs max.

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)									
PARAMETER	SYMBOL	VT3060G	VFT3060G	VBT3060G	VIT3060G	UNIT			
Max. repetitive peak reverse voltage	Max. repetitive peak reverse voltage			60					
Max. average forward rectified current	per device		30						
(fig. 1)	per diode	I _{F(AV)}	15						
Peak forward surge current 8.3 ms single has superimposed on rated load	alf sine-wave	I _{FSM}	150			А			
Non-repetitive avalanche energy at T _J = 25 °C, L = 60 mH per diode		E _{AS}	120				mJ		
Peak repetitive reverse current at $t_p = 2 \mu s$, 1 kHz, $T_J = 38 ^{\circ}\text{C} \pm 2 ^{\circ}\text{C}$ per dic	ode	I _{RRM}	M 1.0				Α		
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min		V _{AC}	1500				V		
Operating junction and storage temperature range			- 55 to + 150						



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PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Breakdown voltage	$I_R = 1.0 \text{ mA}$	T _A = 25 °C	V_{BR}	60 (min.)	=	V
Instantaneous forward voltage per diode (1)	I _F = 5 A	T _A = 25 °C T _A = 125 °C	V _F	0.49	-	V
	I _F = 7.5 A			0.53	-	
	I _F = 15 A			0.65	0.73	
	I _F = 5 A			0.40	-	
	I _F = 7.5 A			0.46	-	
	I _F = 15 A	1		0.61	0.69	
Reverse current per diode (2)	V _R = 60 V	T _A = 25 °C T _A = 125 °C	I _R	- 14	850 40	μA mA

Notes

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)								
PARAMETER		SYMBOL	VT3060G	VFT3060G	VBT3060G	VIT3060G	UNIT	
Typical thermal resistance	per diode	$R_{ hetaJC}$	3.2	6.2	3.2	3.2	°C/W	
	per device		1.9	5.0	1.9	1.9	C/VV	

ORDERING INFORMATION (EXAMPLE)									
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE				
TO-220AB	VT3060G-E3/4W	1.88	4W	50/tube	Tube				
ITO-220AB	VFT3060G-E3/4W	1.76	4W	50/tube	Tube				
TO-263AB	VBT3060G-E3/4W	1.39	4W	50/tube	Tube				
TO-263AB	VBT3060G-E3/8W	1.39	8W	800/reel	Tape and reel				
TO-262AA	VIT3060G-E3/4W	1.45	4W	50/tube	Tube				

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

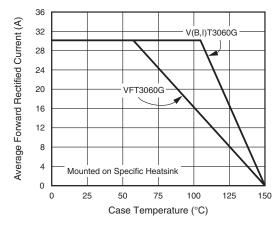


Fig. 1 - Maximum Forward Current Derating Curve

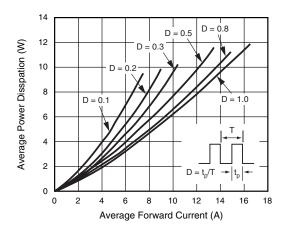


Fig. 2 - Forward Power Dissipation Characteristics Per Diode

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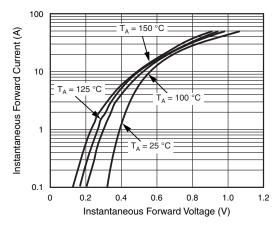


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

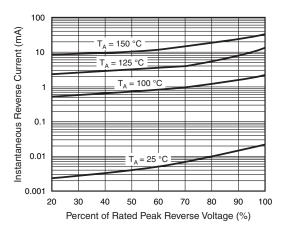


Fig. 4 - Typical Reverse Characteristics Per Diode

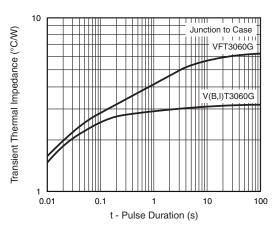


Fig. 5 - Typical Transient Thermal Impedance Per Diode

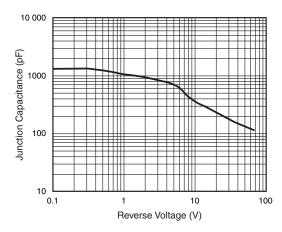
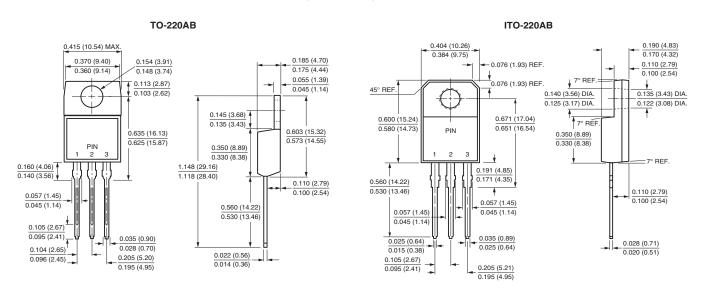


Fig. 6 - Typical Junction Capacitance Per Diode

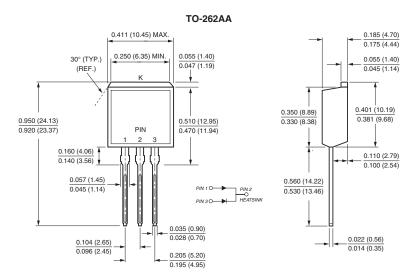
PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



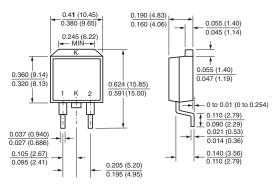


VT3060G, VFT3060G, VBT3060G, VIT3060G

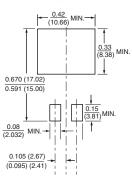
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TO-263AB



Mounting Pad Layout





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